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# **BC368**



# **NPN General Purpose Amplifier**

This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 1.5 A. Sourced from Process 37.

## **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	20	V
V <sub>CES</sub>	Collector-Base Voltage	25	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current - Continuous	2.0	Α
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

#### **Thermal Characteristics** TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		BC368	-
P <sub>D</sub>	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

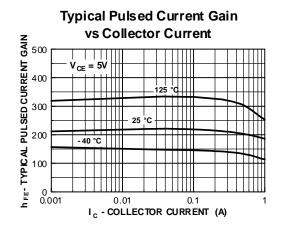
# **NPN General Purpose Amplifier**

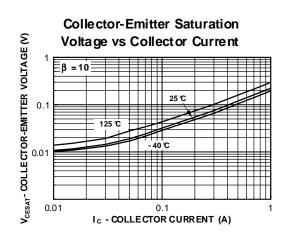
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Symbol	Parameter	Test Conditions	Min	Max	Units
	RACTERISTICS				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	20		V
V <sub>(BR)CEO</sub>	Collector-Base Breakdown Voltage	$I_C = 100 \mu\text{A}, I_E = 0$	25		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \mu\text{A}, I_C = 0$	5.0		V
I <sub>CBO</sub>	Collector-Cutoff Current	V <sub>CB</sub> = 25 V, I <sub>E</sub> = 0 V <sub>CB</sub> = 25 V, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C		10 1.0	μA mA
I <sub>EBO</sub>	Emitter-Cutoff Current	V <sub>EB</sub> = 5.0 V, I <sub>C</sub> = 0		10	μΑ
ON CHAR	ACTERISTICS DC Current Gain	$\begin{split} I_{C} &= 5.0 \text{ mA}, \ V_{CE} = 10 \text{ V} \\ I_{C} &= 0.5 \text{ A}, \ V_{CE} = 1.0 \text{ V} \\ I_{C} &= 1.0 \text{ A}, \ V_{CE} = 1.0 \text{ V} \end{split}$	50 85 60	375	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_C = 1.0 \text{ A}, I_B = 100 \text{ mA}$		0.5	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	$I_C = 1.0 \text{ A}, V_{CE} = 1.0 \text{ V}$		1.0	V
SMALL SI	GNAL CHARACTERISTICS				

f = 35 MHz

# **Typical Characteristics**

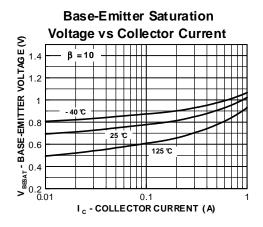


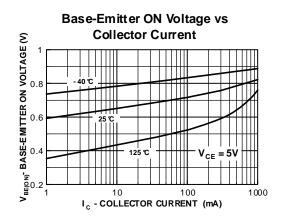


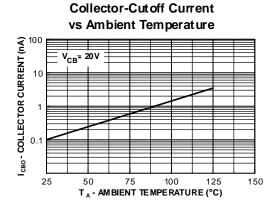
## **NPN General Purpose Amplifier**

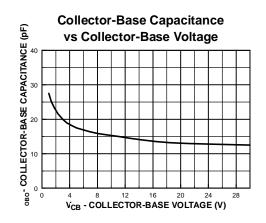
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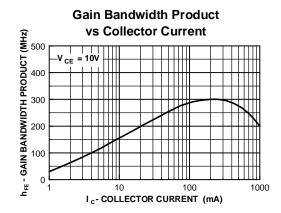
# Typical Characteristics (continued)

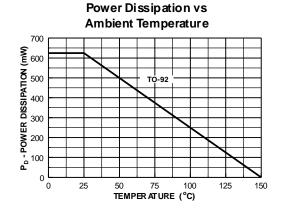












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